Ferromagnetic Shape Memory Alloys II



Edited by V. A. Chernenko J. M. Barandiaran

ttp TRANS TECH PUBLICATIONS

Ferromagnetic Shape Memory Alloys II

Ferromagnetic Shape Memory Alloys II



Selected, peer reviewed papers from the 2nd International Conference on Ferromagnetic Shape Memory Alloys (ICFSMA2009), held at the University of Basque Country, Bilbao, Spain July 1-3, 2009

Organized by the University of the Basque Country and the ACTIMAT Consortium

Edited by:

V. A. Chernenko J. M. Barandiaran

地 TRANS TECH PUBLICATIONS LTD Switzerland • UK • USA Copyright © 2010 Trans Tech Publications Ltd, Switzerland

All rights reserved. No part of the contents of this publication may be reproduced or transmitted in any form or by any means without the written permission of the publisher.

Trans Tech Publications Ltd Laubisrutistr. 24 CH-8712 Stafa-Zurich Switzerland http://www.ttp.net

Volume 635 of Materials Science Forum ISSN 0255-5476

Full text available online at http://www.scientific.net

Distributed worldwide by

Trans Tech Publications Ltd Laubisrutistr. 24 CH-8712 Stafa-Zurich Switzerland

Fax: +41 (44) 922 10 33 e-mail: sales@ttp.net and in the Americas by

Trans Tech Publications Inc. PO Box 699, May Street Enfield, NH 03748 USA

Phone: +1 (603) 632-7377 Fax: +1 (603) 632-5611 e-mail: sales-usa@ttp.net

Printed in the Netherlands

Chairmen

Volodymyr A. Chernenko, Chair Jose Manuel Barandiarán, Co-Chair

International scientific committee

Stefano Besseghini, Italy Volodymyr A. Chernenko, Spain Peter Entel, Germany Simo-Pekka Hannula, Finland Laurent Hirsinger, France Tomoyuki Kakeshita, Japan Ibrahim Karaman, USA Victor A. L' vov, Ukraine Pratip K. Mukhopadhyay, India Peter Müllner, USA Antoni Planes, Spain Ludwig Schultz, Germany Guangheng H. Wu, China Yinong Liu, Australia Oleg Heczko, Czech Republic

Organizing committee

Volodymyr A. Chernenko, UPV/EHU, Bilbao Jose Manuel Barandiarán, UPV/EHU, Bilbao Patricia Lázpita, UPV/EHU, Bilbao Jon Gutiérrez, UPV/EHU, Bilbao Jaume Pons, UIB, Palma de Mallorca Blanca Hernando, Universidad de Oviedo, Oviedo Lluis Mañosa, Universitat de Barcelona, Barcelona Jose Ignacio Pérez de Landazabal, UPN, Pamplona Jorge Feuchtwanger, UPV/EHU, Bilbao Alfredo García, UPV/EHU, Bilbao

UPV/EHU: Universidad del País Vasco/Euskal Herriko Unibertsitatea UIB: Universitat de les Illes Balears UPN : Universidad Pública de Navarra

Sponsors and Exhibitors

a) Public Institutions:



University of the Basque Country

Basque Government

Spanish Ministry of Science

b) Industrial and technical sponsors and exhibitors:



ACTIMAT Consortium

Adaptamat

Mateck GmbH

Karlsruhe Institute of Technology

Conference photo





See the list of attendees on the next page

Attendees in the photo

- 1. P.Müllner (USA) 2. T. Eichhorn (Germany) 3. U. Stuhr (Switzerland) 4. J. Gutiérrez (Spain) 5. D.Y. Cong (China) 6. S. Fähler (Germany) 7. S. Kaufmann (Germany) 8. V.Recarte (Spain) 9. M. Pötschke (Germany) 10. I. Rodrigues (Spain) 11. D. Merida (Spain) 12. L.Straka (Czech Rep) 13. V. Prida (Spain) 14. L. Hirsinger (France) 15. A. Sozinov (Finland) 16. P. K. Mukhopadhyay (India) 17. S.-P. Hannula (Finland) 18. P. Makela (Finland) 19. V.A. Lvov (Ukraine) 20. V. Toyos (Spain) 21. B. Krevet (Germany) 22. J. Pons (Spain) 23. J. Feuchtwanger (Spain) 24. H.Sehitoglu (USA) 25. E. Palacios (Spain) 26. H.Morawiec (Poland) 27. S. Besseghini (Italy) 28. K.Prusyk (Poland) 29. S. Roth (Germany) 30. C.Hürrich (Germany) 31. S. R. Barman (India) 32. J. Liu (Germany) 33. F. Masdeu (Spain) 34. J. Zurbitu (Spain) 35. A. Böhm (Germany) 36. E. Cesari (Spain) 37. V. Sanchez-Alarcos 38. R. Santamarta (Spain) 39. S.Fabbrici (Italy) 40. C. P. Sasso (Italy)
 - 41. I. Pérez-Landazábal (Spain)

42. F. Plazaola (Spain) 43. K. Korpiola (Finland) 44. D. Shilo (Israel) 45. Ll. Mañosa (Spain) 46. R. Kanth (India) 47. M. Kohl (Germany) 48. D. Stroz (Poland) 49. T. Besseghini (Italy) 50. A. Besseghini (Italy) 51. D. E. Soto-Parra (Mexico) 52. O. Heczko (Czech Rep) 53. M.Nagasako (Japan) 54. G. Wu (China) 55. D. Kellis (USA) 56. L. Righi (Italy) 57. S.N. Kaul (India) 58. J.L. Sanchez-Llamarazes (Spain) 59. J.J. Suñol (Spain) 60. C. Picornell (Spain) 61. I. I.Kositsyna (Russia) 62. M.L. Sanchez (Spain) 63. C. Seguí (Spain) 64. Y. Ge (Finland) 65. T. Fukuda (Japan) 66. G. Jakob (Germany) 67. S.M.A. Elkatlawy (Egypt) 68. A. García (Spain) 69. J. Alonso (Spain) 70. M.L.Corró (Spain) 71. P. Lázpita (Spain) 72. M. Ferro (Spain) 73. S. Kustov (Spain) 74. J.Rodriguez (Spain) 75. J. M. Barandiarán (Spain) 76. D. Jain (India) 77. V.A. Chernenko (Spain) 78. R. Kainuma (Japan) 79. S. Majumdar (India) 80. B. Spasova (Germany) 81. K. Ullakko (Finland)

Preface

Recent progress in research and development of ferromagnetic shape memory alloys, accompanied by an exponential publication record, proves the enormous interest of scientists and engineers in such smart materials, which show outstanding performances as sensors and actuators alongside other capabilities. Recent results obtained in this rapidly evolving interdisciplinary field have been extensively presented during the Second International Conference on Ferromagnetic Shape Memory Alloys (ICFSMA2009) held on 1–3 July 2009 in Bilbao, Spain. The conference was organized by the University of Basque Country and Actimat Consortium, Bilbao, Spain. The topics for discussions were tentatively divided six groups:

A. Basic phenomena and theory

B. Structure and magnetic properties

C. Magnetomechanics and magnetocaloric effect

D. Thin films and composites

E. Modeling and simulations

F. Processing and engineering

These topics have been covered in nearly one hundred invited, oral and poster regular contributions.

This volume contains a selection of peer-reviewed papers presented at ICFSMA'09, which are grouped according to the conference topics. The volume bears the same title as the Proceedings of the first ICFSMA'07 held in Kolkata, India, symbolizing the continuity of a new chain of international scientific meetings dedicated to the aforementioned research field and topics.

We hope this volume will be a useful guide for physicists, materials scientists, engineers and materials producers engaged in the field of the ferromagnetic shape memory alloys and smart materials.

The conference was attended by over 85 participants from 17 countries. The very large attendance to oral and poster sessions and the long and deep informal discussions were clear manifestations of a successful event that deserved very positive feedback from the delegates.

We are thankful to all authors and reviewers who made possible the present volume. We thank the members of the International Scientific Committee for their help and active contributions and to the Local Organizing Committee, who managed the well-coordinated course of the conference. We also wish to thank all sponsors and exhibitors.

> V.A. Chernenko Conference Chairman

J.M. Barandiarán Conference Co-Chairman

Table of Contents

Committees Sponsors and Exhibitors Conference Photo and list of attendees Preface

A. Basic Phenomena and Theory

Fundamental Aspects of Magnetic Shape Memory Alloys: Insights from <i>Ab Initio</i> and	
Monte Carlo Studies	
P. Entel, M.E. Gruner, A. Dannenberg, M. Siewert, S.K. Nayak, H.C. Herper and V. Buchelnikov	3
The Symmetry-Conforming Theory of Martensite Aging	
V.A. L'vov, A. Kosogor, O. Söderberg and S.P. Hannula	13

B. Structure and Magnetic Properties

NiMn-Based Metamagnetic Shape Memory Alloys R Kainuma K Ito W Ito R Y Umetsu T Kanomata and K Ishida	23
Incommensurate and Commensurate Structural Modulation in Martensitic Phases of	25
FSMA	
L. Righi, F. Albertini, A. Paoluzi, S. Fabbrici, E. Villa, G. Calestani and S. Besseghini	33
Structural, Thermal and Magnetic Properties of Ga Excess Ni-Mn-Ga S. Singh, S. Bhardwaj, A.K. Panda, V.K. Ahire, A. Mitra, A.M. Awasthi and S.R. Barman	43
Structural Relation between the X-Phase and other Phases in Ni ₂ MnGa T. Kakeshita, T. Fukuda, T. Terai, T. Osakabe and K. Kakurai	49
Positron Annihilation Spectroscopy Study of NiMnGa Modulated and Non-Modulated	
Martensitic Phases D. Merida, J.A. García, E. Apiñaniz, F. Plazaola, V. Sánchez-Alarcos, J.I. Pérez-Landazábal and V. Recarte	55
X-Ray Diffraction Reciprocal Space Mapping Study of Modulated Crystal Structures in 10M Ni-Mn-Ga Martensitic Phase Y L. Ge. I. Aaltio, O. Söderberg and S.P. Hannula	63
Domain Structures across the Martensitic Transformation in Ni $_{2+x}$ Mn $_{1-x}$ Ga D. Jain, S. Banik, L.S. Sharath Chandra, S.R. Barman, R. Nath and V. Ganesan	69
Study of Co-Ni-Al Alloys with Magnetically Controlled Shape Memory Effect I.I. Kositsyna and V.A. Zavalishin	75
Annealing Effect on Martensitic Transformation and Magneto-Structural Properties of Ni-	
Mn-In Melt Spun Ribbons T. Sánchez, J.L. Sánchez Llamazares, B. Hernando, J.D. Santos, M.L. Sánchez, M.J. Perez, J.J. Suñol, R. Sato Turtelli and R. Grössinger	81
Influence of Magnetic Field on Magnetostructural Transition in Ni _{46.4} Mn _{32.8} Sn _{20.8} Heusler Allov	
P. Lázpita, V.A. Chernenko, J.M. Barandiarán, I. Orue, J. Gutiérrez, J. Feuchtwanger and J.A. Rodriguez-Velamazán	89
Magnetic and Martensitic Transitions in Ni ₂ Mn _{1+x} Sn _{1-x} Alloys S. Chatterjee and S. Majumdar	97
Effect of Co and Mn Doping on the Martensitic Transformations and Magnetic Properties of Fe-Pd Ferromagnetic Shape Memory Alloys V. Sánchez-Alarcos, J.I. Pérez-Landazábal and V. Recarte	103
Structural, Magnetic and Transport Properties of Ni-Fe-Al Alloys S.N. Kaul, A.C. Abhyankar, D.V. Sridhar Rao, K. Muraleedharan, A.K. Nigam and L. Fernández Barquín	111

C. Magnetomechanics and Magnetocaloric Effect

Recent Developments in Ni-Mn-Ga Foam Research	
P. Müllner, X.X. Zhang, B. Yuttanant, C. Witherspoon, M. Chmielus and D.C. Dunand	119
Magnetoelastic Coupling in Ni-Mn-Ga Magnetic Shape Memory Alloy O Heczko	125
Evaluation of Magnetostriction of the Single-Variant Ni-Mn-Ga Martensite	120
V.A. L'vov, I. Glavatskyy and N. Glavatska	131
Theoretical Modeling of Magnetocaloric Effect in Heusler Ni-Mn-In Alloy by Monte Carlo Study	
V. Buchelnikov, V.V. Sokolovskiy, S. Taskaev and P. Entel	137
D. Thin Films and Composites	
Recent Progress in FSMA Microactuator Developments	
M. Kohl, S. Reddy Y., F. Khelfaoui, B. Krevet, A. Backen, S. Fähler, T. Eichhorn, G. Jakob and A. Mecklenburg	145
Structural and Magnetic Properties of Epitaxial Ni ₂ MnGa Thin Films T. Eichhorn and G. Jakob	155
Magnetically Anisotropic Ni ₂ MnGa Thin Films: Coating Glass and Si Micro-Cantilevers	
Substrates V Madurga C Favieres and I Vergara	161
Fabrication and Magnetic Properties of CoNiAl Ferromagnetic Shape Memory Alloy Thin	101
R.B. Kanth, D. Bhattacharjya and P.K. Mukhopadhyay	167
E. Modeling and Simulations	
Thermodynamic Modelling of Ferromagnetic Shape Memory Actuators	1.5.5
B. Krevet and M. Kohl	175
B. Spasova and H.H. Gatzen	181
F. Processing and Engineering	
Extruded Rods with <001> Axial Texture of Polycrystalline Ni-Mn-Ga Alloys	100
H. Morawiec, J. Lelątko, T. Goryczka, K. Prusik, S. Piechota and D. Stróż	189
Twinning Behaviour of Textured Polycrystalline Ni-Mn-Ga Alloy after Hot Extrusion R. Chulist, A. Böhm, T. Lippmann, W. Skrotzki, W.G. Drossel and R. Neugebauer	195
Nano-Positioning with Ferromagnetic Shape Memory Alloy Actuators E. Asua, J. Feuchtwanger, A. García-Arribas, V. Etxebarria and J.M. Barandiarán	201

A. Basic Phenomena and Theory

Fundamental Aspects of Magnetic Shape Memory Alloys: Insights from ab initio and Monte Carlo Studies

Peter Entel^{1,a}, Markus E. Gruner¹, Antje Dannenberg¹, Mario Siewert¹, Sanjeev K. Nayak¹, Heike C. Herper¹, and Vasiliy D. Buchelnikov² ¹Physics Department, University of Duisburg-Essen, 47048 Duisburg, Germany ²Physics Department, Chelyabinsk State University, Chelyabinsk 454021, Russia ^aentel@thp.uni-duisburg.de

Keywords: Ferromagnetic Heusler alloys. Magnetic shape memory effect. Ab initio calculations.

Abstract. Ferromagnetic Heusler alloys like Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb), which undergo a martensitic phase transformation, are on the edge of being used in technological applications involving actuator and magnetocaloric devices. The other class of ferromagnetic full Heusler alloys like Co-Mn-Z (Z = Al, Si, Ga, Ge, Sn) not undergoing a structural phase transition, are half-metals (in contrast to the Ni-based systems) with high spin polarization at the Fermi level and are of potential importance for future spintronics devices. On the basis of recent *ab initio* calculations, we highlight the main differences between the two classes of Heusler based materials.

Introduction

Since the pioneering work of Webster et al. [1, 2], there has been new interest in a particular class of ferromagnetic (FM) shape memory alloys (MSMA), which undergo a structural transformation from the FM high-temperature cubic L2₁ phase to the tetragonally distorted 5M or 7M phase, which shows an extremely large strain of up to 10% in an external field of less than 1 Tesla [3-6]. This is the basis of the one- and two-way shape memory effect (SME) due to magnetically controlled martensitic transformation as experimentally observed [7]. By now, these magneto-induced shape memory mechanisms have in detail been investigated for mono- and polycrystalline Ni-Mn-Fe-Ga samples [7-9] including twin boundary motion in the modulated phases under the impact of the external magnetic field [10].

Nevertheless, fundamental questions regarding the energetics of twin boundary motion in relation to the local atomic structure, chemical composition, magnetic state and magnetic anisotropy as well as the electronic structure (see Ref. [11] for an overview) have still to be worked out. What remains to be done from a practical point of view regarding the use of MSMA and magneto-caloric (MCE) devices is to find new FM Heusler alloys which allow *higher working temperatures*.

Regarding Heusler-based spintronics materials like Co-Mn-Fe-Si, the practical point of view in relation to application purposes is to maintain half-metallicity in the samples to achieve high magnetoresistance values at room temperatures. From a theoretical point of view the realization of half-metallic Heusler alloys, with a 100% spin polarization at the Fermi level depends on details of the electronic structure and the valence electron number per atom, e/a, limiting the possible candidates, for instance, see Galanakis et al. [12, 13]. Information on the properties of spintronics materials may be taken from Refs. [14, 15].

In this paper, we present a few new basic results of both types of Heusler alloys, based on *ab initio* calculations and finite temperature simulations using statistical models like the Heisenberg and q-state Potts model [16]. Although the emphasis in this paper mainly concerns MSMA, a simultaneous discussion of electronic and magnetic features of spintronics materials gives a deeper understanding of basic features determining the behavior of both types of Heusler systems, i.e., martensitically unstable (MSMA) and stable FM Heusler alloys (suited for spintronics applications). We will show that the number of valence electrons per atom, e/a, in conjunction with the variation of the spin magnetic moments with change in temperature are decisive parameters when considering the martensitic instability in MSMA.

First-Principles Calculations of the Electronic and Magnetic Properties of Heusler Alloys

There is a series of electronic structure calculations of MSMA and spintronics materials available from the literature, for example, see Refs. [11, 12, 17-25], emphasizing the importance of a band Jahn-Teller effect for the structural instability (martensitic transformation) in MSMA and the existence of a band gap around the Fermi energy, E_F , in the minority-spin channel of materials of interest for spintronics.

We have repeated some of the electronic structure calculations using VASP [26, 27] and show in Fig. 1 and 2 the resulting spin-down band structures of the spintronics material Co_2MnGe and the MSMA Ni₂MnGa with element-specific projections (left) and symmetry assigned bands (right).



Fig. 1: Minority-spin band structure of Co_2MnGe projected onto the element-specific contributions (left) and symmetry-assigned contributions (right), showing the formation of the *half-metallic gap* around the Fermi energy.



Fig. 2: Minority-spin band structure of Ni₂MnGa projected onto the element-specific contributions (left) and symmetry-assigned contributions (right), showing difference that arises compared to the case of Co₂MnGe like the closing of the energy gap at E_F .

We find in the majority-spin bands either Co or Ni and Mn near the Fermi energy E_F , while in the minority-spin bands, the states in the vicinity of E_F are – apart from the Γ point - nearly entirely Co- or Ni-*d* states of e_g symmetry. This scenario leads in case of Ni₂MnGa to the martensitic instability.

In Fig. 3, the electronic density of states (DOS) curves are depicted showing the formation of a gap in the minority-spin channel of Co₂MnGe of the order of 0.4 eV yielding a half-metal at zero temperature, while for Ni₂MnGa, this gap is partially filled with Mn- and Ni- e_g and t_{2g} states and is pushed below E_F by 0.75 eV, because of the filling of the band structure by one additional valence

electron per formula unit as compared to Co₂MnGe.

Note that in Ni₂MnGa, we find a pronounced peak of Ni- e_g states in the minority-spin DOS right below E_F , see Fig. 3. This is a highly unstable situation and the system can lower its energy by a slight tetragonal distortion which pushes this Ni- e_g peak by approximately 1 eV above E_F and redistributes the electrons in lower energy states. This effectively pushes the gap-like structure towards E_F (but does not yield a half-metallic state because there are states in the gap filled by mainly Ni-*d* electrons). This Jahn Teller like effect (which is first discussed by Ayuela *et al.* by means of first-principles DOS calculations [19]) is in the present case associated with e_g states and not with the t_{2g} states. In other systems this often leads to a triplet ground state of ${}^{3}t_{1u}$ configuration which is known to be unstable against a Jahn-Teller distortion [28, 29] (note also that the actual symmetry assignment of the lower and upper gap states in Co₂MnGe is t_{1u} (occupied) and e_u (unoccupied) [13].) This electronic scenario is the origin of the martensitic instability in Ni₂MnGa occurring at 220 K in the FM state below the Curie temperature at 376 K.



Fig. 3: Total and element-projected electronic density of states curves of Co₂MnGe (left) and Ni₂MnGa (right) showing the formation of the energy gap at E_F for the Co-based Heusler compound. For the Ni-based system a peak at E_F appears which mainly consists of Ni- e_g states responsible for the Jahn-Teller like distortion.

Now, the gap of the full-Heusler alloys is still a rather subtle point [19]. When considering Ni₂MnGa in distinction to Co₂MnGe, a close look at the behavior of the minority-spin band structure reveals that it is not a mere band filling effect but also shows that hybridization of states near E_F is significantly different. In both compounds, the Co(Ni) atoms occupy sites of octahedral symmetry which splits the *d*-states into e_g , e_u , t_{2g} and t_{1u} , which are doubly and triply degenerated. In the Co-based Heusler alloy, the fact that the e_u and t_{1u} states arising from octahedral symmetry cannot hybridize with the Mn-*d* or Ge-*p* states (with Mn and Ge sitting at the tetrahedral sites of the L2₁ crystal structure) together with the right valence electron number of e/a = 7.25 (in contrast to 7.5 in case of Ni₂MnGa) causes the formation of an energy gap, whereby E_F comes to lie between the e_u and t_{1u} levels [19]. Due to this half-metallicity, the spin polarization *P* at E_F arises solely from the majority-spin states, i.e., P = 100%, while P = -25.6% in case of Ni₂MnGa. It would be interesting to know whether FM Heusler alloys were possible, which exhibit the MSME as well as a

large *P* value (although in general, large *P* may mean low Fermi surface nesting inhibiting modulated phases). If we consider the critical values e/a = 7.25 (Co₂MnGe) and e/a = 7.5 (Ni₂MnGa) one may conceive an alloy of composition CoNiMnGe_{0.5}Ga_{0.5} with e/a = 7.375 in between a half-metallic and metallic system. Recent *ab initio* calculations of a similar system, CoNiMnGa with L2₁-like structure and e/a = 7.25, shows the existence of a gap right below E_F (and a larger spin polarization than Ni₂MnGa) and no tendency for a martensitic instability. The corresponding DOS is shown in Fig. 4. In a very similar way, one may systematically try to obtain new Heusler alloys of interest for spintronics as well as MSM devices by combining systems from the series Co-Mn-Z (Z = Al, Si, Ga, Ge, Sn) with those from Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb).



Fig. 4: Density of states of cubic NiCoMnGe (e/a = 7.5) and NiCoMnGa (e/a = 7.25) – close to half-metallic behavior; the latter system does not show tendency for a martensitic instability.

Origin of Martensitic Transformation in Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb) Heusler Alloys

The ferromagnetic Heusler systems Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb) all exhibit a martensitic instability of which Ni-Mn-Ga is the only one showing the instability at the stoichiometric composition Ni₂MnGa. In fact, near-stoichiometric compounds of Ni₂MnGa show a series of reversible phase transformations with decreasing temperature from the high-temperature cubic L2₁ structure to premartensitic modulated 3M and then to the modulated martensitic phases 5M and 7M (with a tetragonal distortion c/a = 0.94) and finally to the non-modulated tetragonal L1₀ structure with c/a = 1.26 at very low temperatures. Such sequence of transitions was reported by Chernenko *et al.* for three alloys with slightly different off-stoichiometric compositions; for these diagram of Ni-Mn-Ga for Ni-excess concentration [11] and the schematic phase diagram of Ni-Mn-Z (Z = Ga, In, Sn, Sb) of the martensitic transformation temperatures as a function of e/a [31].

In case of stoichiometric composition, we find e/a = 7.5 (Ni₂MnGa and Ni₂MnIn), e/a = 7.75 (Ni₂MnSn) and e/a = 8 (Ni₂MnSb), showing that, apart from Ni₂MnGa, the other MSMA only undergo a structural transformation for off-stoichiometric compositions.

With respect to the origin of the structural instability in the MSMA, attention has to be paid to the possible electronic and phononic driving forces. For simplicity, limiting the discussion to prototype Ni₂MnGa, we observe electrons with $e_g(e_u)$ symmetry contributing to the instability by Fermi surface nesting associated with the corresponding peak in the minority DOS, see Fig. 3 and the discussion in Ref. [11]. The system can lower its energy by a redistribution of electrons and simultaneous shift of this peak to a higher region above E_F . The resulting DOS for the stable martensitic 5M (c/a = 0.94) and non-modulated L1₀ (c/a = 1.25) structures are shown in Fig. 6.



Fig. 5: Phase diagram of Ni-Mn-Ga as a function of Ni-excess concentration (left) showing the Curie temperature (T_C) , the premartensitic (T_P) and the martensitic transformation temperature (T_M) , respectively [11]. Alloys near stoichiometry show the MSME, whereas alloys with merging T_C and T_M exhibit the magnetocaloric effect. The schematic behavior of T_M as a function of e/a for the Ni-Mn-Z (Z = Ga, In, Sn, Sb) alloys is shown in the right panel [31]. The linear behavior of T_M with e/a may partially be explained using a rigid band picture (filling in electrons) in conjunction with fixed spin moment calculations, which allow to model the decrease of magnetization with increasing temperature.

The absence of martensitic instabilities in the other alloys of type Ni-Mn-Z (In, Sn, Sb) at stoichiometric composition may tentatively be related to the fact that in this case, we do not find any trace for Fermi surface nesting. Weak nesting behavior appears, for example in case of Ni-Mn-Sb, at larger values of e/a (> 8) in agreement with the experimental change of T_M with e/a in Fig. 5. However, note that the situation is more complex for the off-stoichiometric alloys, since the shift of T_M away from the stoichiometric composition to larger values of e/a is not a mere band-filling effect since hybridization changes in a subtle way around the Fermi level. Also, the influence of phonons on the martensitic transformation may be more important than in case of stoichiometric samples since the lattice becomes elastically softer for the disordered alloys. This is obvious from the behavior of the total energy as a function of tetragonal distortion, c/a, showing a change of the energies of cubic and martensitic phases relatively to each other.

However, the situation is more complex, since at $T_M = 220$ K (Ni₂MnGa) the magnetization has decreased and is different from its ground-state value. This pushes the e_g -peak in the spin-down DOS further away from the Fermi level to lower energies. Since the nesting vectors vary continuously with the magnetization, this means that part of the nesting behavior of the spin-down electrons at E_F is lost. However, for this reduced magnetization at finite temperatures we find simultaneously the appearance of a *weaker* Fermi surface nesting of the majority-spin electrons, which was already discussed in Ref. [32]. So, it seems that Fermi surface nesting in both spin channels is required to provoke the structural transformation from the FM cubic L2₁ phase to the modulated premartensitic phase. Since different nesting vectors come from the different spin channels, the premartensitic phase of Ni_2MnGa has no well defined modulated structure and a reshuffling of the atoms lowers the energy further driving the martensitic transformation to the 5M structure.



Fig. 6: Total and element-projected electronic density of states curves of 5M modulated tetragonal (c/a = 0.94) Ni₂MnGa (left) and nonmodulated tetragonal (c/a = 1.25) Ni₂MnGa (right) showing that in both cases the Fermi energy comes to lie at a relatively favorable position.

With respect to the contributions of lattice vibrations to the premartensitic and martensitic transformation in Ni₂MnGa, the situation is even less clear. Phonons start to soften already in the paramagnetic phase and then harden a bit when approaching the premartensitic phase [33-35] and show very unusual behavior below the martensitic phase transition in the 5M phase [36]. The softening was well reproduced in *ab initio* phonon calculations [37-39]; in particular the first-principles calculations of the different contributions to the free energy of Ni₂MnGa showed that without the magnetic contributions, one fails to get the right sequence of phases at elevated temperatures [40]. Although the displacement fields of the [110] phonons in the cubic L2₁ structure will finally be needed to achieve the transformation to the martensitic phase (with a critical wave vector of q = 0.43 in [110] direction in case of Ni₂MnGa), we believe that the intrinsic instability is related to the simultaneous appearance of nesting behavior in both spin channels in a narrow temperature range fixed by the magnetization of the sysem.

Competing Magnetic Ordering in Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb) Heusler Alloys

Evaluation of magnetic exchange coupling constants of the ferromagnetic Heusler alloys Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb) hints towards a rather complex scenario of competing antiferromagnetic (AF) and FM interactions in the alloys in contrast to half-metals as Co₂MnGe for which the interactions are dominantly ferromagnetic. Intriguingly, this competition of different magnetic ordering tendencies leads to the appearance of multiple magnetic phases as is the case for Ni-Mn-Sb [16, 41]. Typically, the magnetization as a function of temperature, M(T), for the off-stoichiometric alloys Ni-Mn-Z (Z = In, Sn, Sb) shows with decreasing temperature a sudden increase (as in a first-order like transition) from paramagnetic (PM) austenite to FM austenite and a sudden decrease accompanying the martensitic transformation at still lower T. First-principles calculations of the exchange constants, J_{ij} , as a function of the distance between the atoms show that the interaction

between nearest neighbors Co-Mn or Ni-Mn is strongest in all compounds and alloys and plays a decisive role for the value of T_C .

However, the situation is more subtle, since any degree of disorder and tetragonal distortion leads to oscillating behavior of J_{ij} with AF and FM interaction, which mainly is responsible for the rather unusual magnetization curves of the MSMA. There is a series of publications dealing with the *ab initio* evaluation of the J_{ij} using direct and frozen magnon methods, all confirming the oscillating J_{ij} [16, 42-44]. The general trend of how tetragonal distortions or disorder influence the J_{ij} in contrast to the strictly FM interactions in the stoichiometric Co₂MnGe and Ni₂MnGa in the L2₁ structure, is shown in Fig. 7. Now, the unusual trends in M(T) (steep increase and subsequent steep decrease gives rise to the usual and inverse magnetocaloric effect (MCE) [45], which is of technological importance.



Fig. 7: Magnetic exchange interaction coupling constants J_{ij} as a function of the distance between the atoms in units of the lattice constant for Co₂MnGe (top left), Ni₂MnGa (top right), and tetragonally distorted (c/a = 0.95 and c/a = 1.25) Ni₂MnGa (lower two figures).

With respect to finite temperature behavior of spintronics materials, the very high Curie temperatures of Co₂MnGe ($T_C = 900$ K), Co₂MnSi ($T_C = 985$ K) and Co₂FeSi ($T_C = 1100$ K) are rather promising [44]. However, it seems difficult to keep the high magnetoresistance in tunneling devices up to room temperature because of the instability of the compounds or alloys towards

atomic diffusion and anti-site disorder at surfaces or tunnel junctions. This reduces the high spin polarization due to filling of the energy gap with states arising from the disorder. Regarding the MSMA, the difficulty is here that Curie temperatures and martensitic transformation temperatures are too low, preventing, for instance actuators to work at ambient temperatures.

Nevertheless, it may be interesting to evaluate M(T) by using the calculated J_{ii} in Monte Carlo simulations, which is shown in Fig. 8 for the case of Ni₂MnGa (with the J_{ij} taken for the L2₁ structure). Although, as discussed in Ref. [44], the calculated Curie temperatures of MSMA using mean-field theory agree to some extent with the experimental values. However, this is probably not a reliable procedure in case of MSMA with competing magnetic ordering tendencies. In this case, Monte Carlo simulations using the J_{ij} obtained form zero-temperature *ab initio* calculations will certainly yield better results, for details, see the discussion in Ref. [16]. Especially for the offstoichiometric systems like Ni-Mn-In, Ni-Mn-Sn and Ni-Mn-Sb, the AF interactions between the spin moments of Mn atoms on the Mn- and X-sublattice below T_M not only compete with the FM ones but also change in a subtle way with temperature due to the temperature variation of the lattice constants. This, finally, is responsible for the complex magnetic phase diagram of In, Sn and Sb based off-stoichiometric Heusler systems, of which the Sb-system has been discussed in Ref. [41]. (note that a different picture of AF order in stoichiometric Ni₂MnGa and Ni₂MnAl was discussed by Enkovaara et al., where the AF order of the Mn spin moments leads to vanishing magnetization at the Ni sites [45]) Recent measurements of the q-dependence of the neutron scattering cross sections in the austenite (500 K) and martensite (320 K) states of Ni₅₀Mn₄₀Sb₁₀ confirm this scenario and show that the FM reflections start to decrease in the martensitic phase and AF reflections start to increase [46].



Fig. 8: Results of Monte Carlo simulations of the magnetization (normalized to M/f.u.) using the zero-temperature *ab initio* values of exchange coupling constants of cubic L2₁ Ni₂MnGa shown in Fig. 7. From the extrapolation of $M^3(T)$ to M = 0, a Curie temperature of 375 K is estimated, which is in perfect agreement with the experimental value.

Future of Spintronics, Magnetic Shape Memory and Magnetocaloric Systems

As already suggested in this paper, combination of well-established spintronics materials with high Curie temperatures like Co_2MnGe with MSMA and MCE materials like Ni-Mn-Z (Z = Al, Ga, In, Sn, Sb) may yield new and interesting phenomena like a near half-metal system undergoing a martensitic transformation, although we find the trend that half-metallicity and structural instability seem to exclude each other. Preliminary results for the DOS of NiCoMn(Ga, Ge) are shown in Fig. 4. The DOS in Fig. 4 seems to indicate that one would need a compound with 7.25 < e/a < 7.5 in